



CHARACTERISTICS OF MOSFET

MODEL - MS - 08.

FEATURES:

- ** Two Power Supplies (Regulated, Continuously Variable and Short – circuiting proof), suitable for the experimental board are builtin.
- ** Circuit is printed and component are mounted on the top of the decorated sunmica bakelite sheet to give better and clear understanding.
- ** Patch cords suitable to the terminals are supplied with the board for the easy inter connections and longer working life of terminals.



- ** A complete working manual containing theory, circuit details and operating instructions, is supplied with the experimental board.
- ** A ON/OFF switch with indicating lamp is provided.

EXPERIMENT:

By the experimental set – up, it will be examinal the relationship between:

- 1. The Gate to Source Voltage (V_{GS}) .
- 2. The Gate Drain circuit (I_D) .
- 3. The Drain to Source Voltage (V_{DS}) .

Also it will be measure the corresponding V_{GS} , I_D and V_{DS} values and graphically plot them to form a set of drain characteristics values.

OTHER APPARATUS REQUIRTED:

1. Digital Voltmeter. 0-20, Volt. One No. (Builtin)

2. Digital Milliammeter. 0-20, mAmp. One No. (Builtin)

There may be any change in specification due to continuous R & D without notice.